



HIGH NOISE REDUCTION 10 Mbps OPEN COLLECTOR OUTPUT TYPE 5 PIN SOP OPTOCOUPLER

PS9714

FEATURES

- HIGH COMMON MODE TRANSIENT IMMUNITY:**
CMH, CML: $\pm 20 \text{ kV}/\mu\text{s}$ TYP
- HIGH SPEED RESPONSE:**
10 Mbps
- HIGH ISOLATION VOLTAGE:**
BV: 2500 Vr.m.s.
- OPEN COLLECTOR OUTPUT TYPE**
- 5 PIN SOP (SMALL OUTLINE PACKAGE)**
- TAPE AND REEL AVAILABLE:**
PS9714-F3, F4: 3500 Pcs/Reel

DESCRIPTION

The PS9714 is an optically coupled isolator containing a GaAlAs LED on the light emitting diode (input) side and a photodiode and a signal processing circuit on the detector (output) side on one chip. The PS9714 is in a plastic SOP (Small Outline Package) type for high density applications.

APPLICATIONS

- MEASUREMENT EQUIPMENT**
- PDP**
- FACTORY AUTOMATION NETWORK**

ELECTRICAL CHARACTERISTICS ($T_A = -40$ to $+85^\circ\text{C}$ unless otherwise specified)

		PART NUMBER	PS9714			
SYMBOLS		PARAMETERS	UNITS	MIN	TYP	MAX
Diode	V _F	Forward Voltage, I _F = 10 mA, T _A = 25°C	V	1.4	1.65	1.9
	I _R	Reverse Current, V _R = 3 V, T _A = 25°C	μA			10
	C _t	Terminal Capacitance, V = 0 V, f = 1 MHz, T _A = 25°C	pF		30	
Detector	I _{OH}	High Level Output Current, V _{CC} = V _O = 5.5 V, V _F = 0.8 V	μA		2	250
	V _{OL}	Low Level Output Voltage, V _{CC} = 5.5 V, I _F = 5 mA, I _O = 13 mA	V		0.2	0.6
	I _{CCH}	High Level Supply Current, V _{CC} = 5.5 V, I _F = 0 mA	mA		3	8
	I _{CCL}	Low Level Supply Current, V _{CC} = 5.5 V, I _F = 10 mA	mA		6.5	11
	I _{FHL}	Threshold Input Current, V _{CC} = 5 V, V _O = 0.8 V, R _L = 350 Ω	%		2.0	5.0
Coupled	R _{i-o}	Isolation Resistance, V _{in-out} = 1kVdc, RH = 40 to 60%, T _A = 25°C	Ω	10 ¹¹		
	C _{i-o}	Isolation Capacitance, V = 0, f = 1 MHz, T _A = 25°C	pF		0.9	
	t _{PHL}	Propagation Delay Time, High → Low ¹ , V _{CC} = 5 V, I _F = 7.5 mA, R _L = 350 Ω T _A = 25°C	ns		40	75
	t _{PLH}	Propagation Delay Time, Low → High ¹ , V _{CC} = 5 V, I _F = 7.5 mA, R _L = 350 Ω T _A = 25°C	ns		55	75
	t _r	Rise Time, V _{CC} = 5 V, I _F = 7.5 mA, R _L = 350 Ω	ns		20	
	t _f	Fall Time, V _{CC} = 5 V, I _F = 7.5 mA, R _L = 350 Ω	ns		10	
	PWD	Pulse Width Distortion, V _{CC} = 5 V, I _F = 7.5 mA, R _L = 350 Ω	ns		30	50
	t _{PSK}	Propagation Skew, V _{CC} = 5 V, I _F = 7.5 mA, R _L = 350 Ω	ns			60
	CMH	Common Mode Transient Immunity at High Level Output ² V _{CC} = 5 V, V _{CM} = 1 kV, T _A = 25°C, I _F = 0 mA, V _O (MIN) = 2 V	kV/μs	10	20	
	CML	Common Mode Transient Immunity at Low Level Output ² V _{CC} = 5 V, V _{CM} = 1 kV, T _A = 25°C, I _F = 7.5 mA, V _O (MAX) = 0.8 V	kV/μs	10	20	

Please see notes on the next page.

ABSOLUTE MAXIMUM RATINGS¹

(TA = 25°C unless otherwise specified)

SYMBOLS	PARAMETERS	UNITS	RATINGS
Diode			
IF	Forward Current	mA	30
VR	Reverse Voltage	V	3
Detector			
Vcc	Supply Voltage	V	7
Vo	Output Voltage	V	7
Io	Output Current	mA	25
Pc	Power Dissipation ²	mW	40
BV	Isolation Voltage ³	V.r.m.s.	2500
TA	Operating Ambient Temp.	°C	-40 to +85
TSTG	Storage Temperature	°C	-55 to +125

Notes:

1. Operation in excess of any one of these parameters may result in permanent damage.
2. Applies to output pin Vo and power supply pin Vcc.
2. AC voltage for 1 minute at TA = 25 °C, RH = 60 % between input and output.

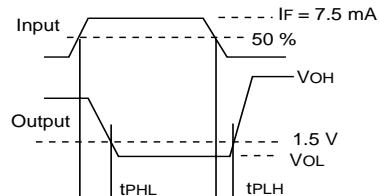
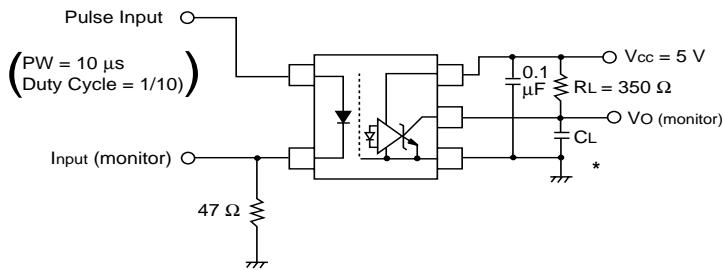
RECOMMENDED OPERATING CONDITIONS

SYMBOLS	PARAMETERS	UNITS	MIN	TYP	MAX
VFL	Low Level Input Voltage	V	0		0.8
IFH	High Level Input Current	mA	6.3		12.5
Vcc	Supply Voltage	V	4.5	5	5.5
N	TTL (loads) (RL = 1kΩ)				5
RL	Pull-up Resistance	Ω	330		4k

(Continued from previous page.)

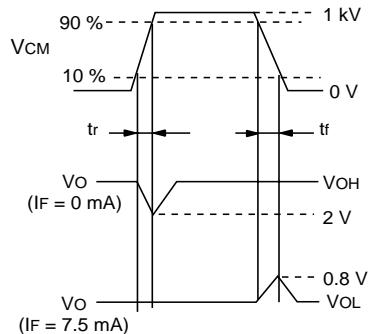
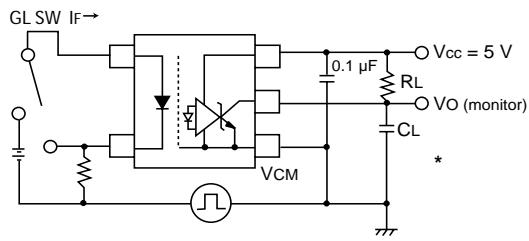
Notes:

1. Test Circuit for Propagation Delay Time:



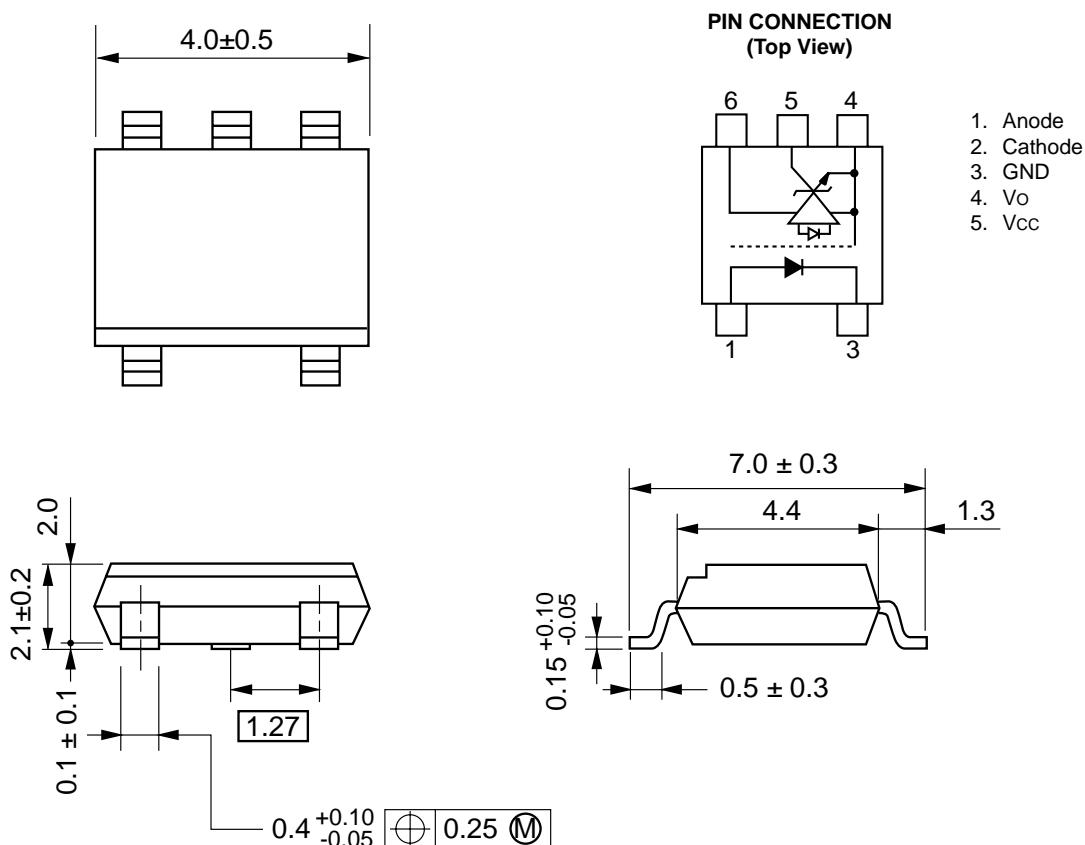
*CL is approximately 15 pF which includes probe and stray wiring capacitance.

2. Test Circuit for Common Mode Transient Immunity:

**USAGE CAUTIONS**

1. Protect against static electricity when handling this product.
2. Bypass capacitor greater than 0.1 μF is used between Vcc and GND near device (lead distance: 10 mm MAX).

PACKAGE OUTLINE (Units in mm)



Life Support Applications

These NEC products are not intended for use in life support devices, appliances, or systems where the malfunction of these products can reasonably be expected to result in personal injury. The customers of CEL using or selling these products for use in such applications do so at their own risk and agree to fully indemnify CEL for all damages resulting from such improper use or sale.

EXCLUSIVE NORTH AMERICAN AGENT FOR NEC RF, MICROWAVE & OPTOELECTRONIC SEMICONDUCTORS

CEL CALIFORNIA EASTERN LABORATORIES • Headquarters • 4590 Patrick Henry Drive • Santa Clara, CA 95054-1817 • (408) 988-3500 • Telex 34-6393 • FAX (408) 988-0279
DATA SUBJECT TO CHANGE WITHOUT NOTICE

Internet: <http://WWW.CEL.COM>

12/13/2001